FEATURES · Glass passivated chip junction

- · Ultrafast recovery time
- · Low switching losses, high efficiency
- Low leakage current
- High forward surge capability
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

MECHANICAL DATA

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commerical grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)										
PARAMETER	SYMBOL	FEPE16AT	FEPE16BT	FEPE16CT	FEPE16DT	FEPE16FT	FEPE16GT	UNIT		
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	V		
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	V		
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	V		
Maximum average forward rectified current at T_{C} = 100 °C	I _{F(AV)}	16					А			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I _{FSM}	200 125				А				
Operating and storage temperature range	T _J , T _{STG}	- 55 to + 150					°C			

TO-220AB

2 x 8.0 A

50 V to 400 V

200 A, 125 A

35 ns. 50 ns

0.95 V, 1.30 V

150 °C

FEPE16XT Series PIN 1 O PIN 2

C CASE

PRIMARY CHARACTERISTICS

I_{F(AV)}

V_{RRM}

IFSM

trr

 V_{F}

T_{.1} max.

FEPE16AT thru FEPE16GT

Vishay General Semiconductor

Dual Common-Cathode Ultrafast Plastic Rectifier

Revision: 30-Jan-13

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RoHS COMPLIANT







Vishay General Semiconductor

ELECTRICAL CHARACTERISTICS ($T_A = 25$ °C unless otherwise noted)											
PARAMETER	TEST CONDITIONS		SYMBOL	FEPE16AT	FEPE16BT	FEPE16CT	FEPE16DT	FEPE16FT	FEPE16GT	UNIT	
Maximum instantaneous forward voltage per diode	8.0 A		V_{F} ⁽¹⁾	ν _F ⁽¹⁾ 0.95				1.30		V	
Maximum DC reverse	at rated	T _C = 25 °C	I _R ⁽²⁾								
current per diode	V _R	T _C = 100 °C	IR (-/	500						- μΑ	
Maximum reverse recovery time per diode	I _F = 0.5 I _{rr} = 0.2	5 A, I _R = 1.0 A, 25 A	t _{rr}	35			50		ns		
Typical junction capacitance per diode	4.0 V,	1 MHz	CJ	85					pF		

Notes

 $^{(1)}\,$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)										
PARAMETER	SYMBOL	FEPE16AT	FEPE16AT FEPE16BT FEPE16CT FEPE16DT FEPE16FT FEPE1					UNIT		
Typical thermal resistance	per diode	R _{0JC}	2.2							
	per device	R _{0JA} ⁽¹⁾	50							

Note

⁽¹⁾ The heat generated must be less than the thermal conductivity from junction-to-ambient: $dP_D/dT_J < 1/R_{\theta JA}$

ORDERING INFORMATION (Example)									
PACKAGE	PREFERRED P/N	PREFERRED P/N UNIT WEIGHT (g)		BASE QUANTITY	DELIVERY MODE				
TO-220AB	FEPE16GT-E3/45	1.92	45	50/tube	Tube				

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

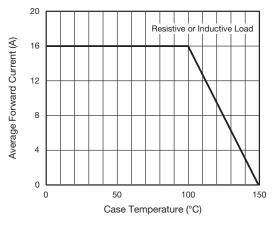
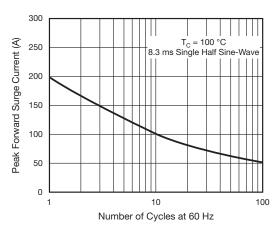
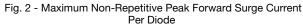


Fig. 1 - Forward Current Derating Curve





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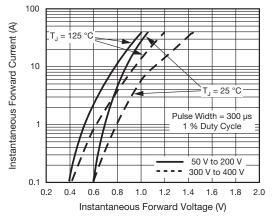


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

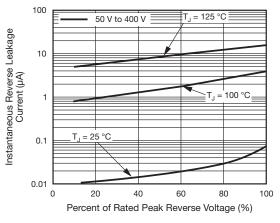
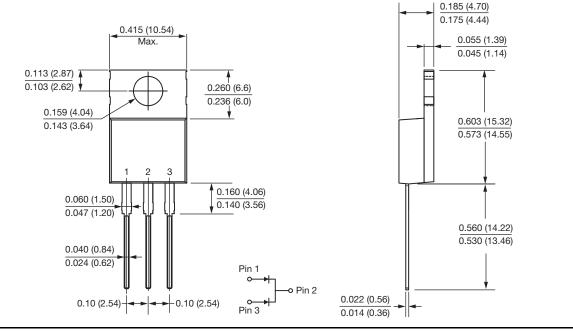


Fig. 4 - Typical Reverse Characteristics Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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FEPE16AT thru FEPE16GT

Vishay General Semiconductor

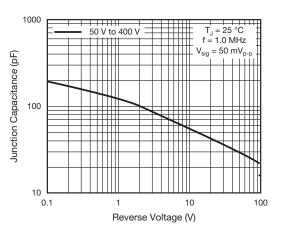


Fig. 5 - Typical Junction Capacitance Per Diode



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